NSN 5961-01-013-9350

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View Online at https://aerobasegroup.com/nsn/5961-01-013-9350 **Inclosure Material:** Metal **Overall Length:** 0.830 inches **Overall Height:** Between 0.250 inches and 0.300 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open and 80.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No **Fiig:**

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